# Ion compositions and energies in inductively-coupled plasmas containing SF<sub>6</sub>

A. N. Goyette\*, Yicheng Wang, and J. K. Olthoff Electricity Division, Electronics and Electrical Engineering Laboratory National Institute of Standards and Technology, Gaithersburg, MD 20899-8113

Inductively-coupled plasmas were generated in pure  $SF_6$  and in  $Ar/SF_6$  and  $O_2/SF_6$  mixtures in a Gaseous Electronics Conference rf reference cell. Absolute total ion current densities, relative ion intensities, and ion energy distributions at the grounded electrode were measured and the influences of pressure, power, and mixture concentration on these quantities examined. In addition to ions derived directly or indirectly from  $SF_6$ , ions resulting from quartz etching and sulfur oxidation contribute moderately to the total ion flux. The dominant sulfur-containing ion observed under most conditions is  $S^+$ , indicating a large degree of  $SF_6$  dissociation.

52.70.Nc, 52.75.Rx

### I. INTRODUCTION

High density plasmas generated in mixtures of  $SF_6$  with rare or simple diatomic gases are involved in many dry etching processes (see, for example, Refs. 1–3). Ion bombardment is a key component of these processes and consequently the determination of the identities, flux, and energies of the ions striking surfaces exposed to etching discharges is necessary in order to understand, accurately model, and ultimately refine the plasma etching process.

We report mass-analyzed ion energy distributions (IEDs), relative ion flux densities, and absolute total ion currents measured using a combined ion energy analyzer-mass spectrometer that samples ions through an orifice in the lower electrode of an inductively-coupled Gaseous Electronics Conference (GEC) rf reference cell. Data are presented for discharges generated in  $SF_6$  and in mixtures of  $SF_6$  with argon and with oxygen.

### II. EXPERIMENT

The discharges studied were generated in a GEC rf reference cell reactor whose upper electrode has been replaced with a five-turn planar rf-induction coil behind a quartz window to produce inductively coupled discharges.<sup>4</sup> The design of the GEC rf reference cell is described in detail elsewhere.<sup>5,6</sup> A quartz annulus

\*Electronic mail: goyette@eeel.nist.gov

developed<sup>7</sup> to allow the generation of plasmas in electronegative gases over a much broader range of pressures and powers was mounted on the upper quartz window of the cell. Mass flow controllers regulated the flow, which was maintained at 3.73  $\mu$ mole/s (5 sccm) for pure SF<sub>6</sub> discharges and 7.45  $\mu$ mole/s (10 sccm) for mixtures of SF<sub>6</sub> with Ar or with O<sub>2</sub>.

The ion sampling arrangement is identical to that used to study inductively-coupled plasmas in several fluorocarbon gases.  $^{7-10}$  Ions are sampled through a 10  $\mu$ m diameter orifice in a 2.5  $\mu$ m thick nickel foil spot-welded into a small counterbore located at the center of the stainless steel lower electrode. For IED measurements, the ions that pass through the orifice are mass selected by the quadrupole mass spectrometer after being energy analyzed by the 45° electrostatic energy selector. The IEDs measured in this manner are essentially ion-flux energy distributions.  $^{11}$ 

Past experience with the ion energy analyzer indicates that the ion transmission is nearly constant over the energy ranges observed here.  $^{11}$  A mass-dependent transmission correction factor, however, was applied to the highest mass ions (mass >40 u) in order to compensate for some decrease in the ion transmission of the quadrupole mass spectrometer with increasing mass. These factors were determined by calibration with rare gas plasmas  $^{12}$  and approach a factor of 22 for the largest mass ion observed,  $\mathrm{SF}_5^+$  at 127 u.

For total ion current measurements, (i.e., all ion current passing through the sampling orifice), the ion optic elements at the front of the ion energy analyzer are biased such that the current passing through the sampling orifice is collected on the extractor element (the first ion optic element behind the electrode surface), and is measured using an electrometer. Total ion current measurements exhibit a reproducibility of  $\pm 15\%$ . The total ion current is partitioned into mass channels according to the mass spectrum of ions. The absolute intensities of the measured IEDs are then determined by scaling the measured values of the ion current for the appropriate mass channel to the total ion current. The ion flux densities presented here are derived by dividing the total measured ion current by the area of the 10  $\mu$ m diameter sampling hole.

# III. RESULTS AND DISCUSSION

Figure 1(a) shows the mass spectrum of ions extracted from a 0.67 Pa (5 mTorr), 200 W inductively-coupled

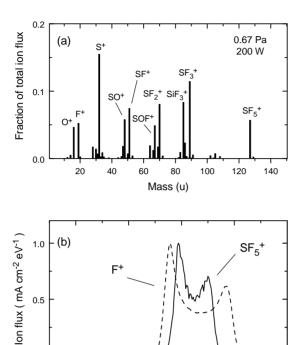


FIG. 1. (a) Mass spectrum of ions striking the grounded electrode in an inductively-coupled SF<sub>6</sub> discharge sustained at 0.67 Pa (5 mTorr) and 200 W. (b) Normalized energy distributions of SF<sub>5</sub><sup>+</sup> (solid lines) and F<sup>+</sup> (dashed lines) ions under these conditions.

20

Ion energy (eV)

30

40

10

0.5

0

plasma (ICP) generated in pure SF<sub>6</sub>. Stable discharges in pure SF<sub>6</sub> could be sustained at 200 W for only a narrow range of pressures around 0.67 Pa (5 mTorr). The ion spectrum contains several ions of similar intensity. These are ions derived directly or indirectly from SF<sub>6</sub> as well as secondary ions resulting from plasma-surface interactions as well as ion-molecule reactions. The predominant ion is S<sup>+</sup> at mass 32 u. The relative ion intensities at masses 32 u and 34 u are consistent with the isotopic abundances of sulfur, indicating that  $O_2^+$  does not contribute significantly to the detected flux of 32 u ions. The predominance of S<sup>+</sup> in the ion spectrum suggests a high degree of SF<sub>6</sub> dissociation in the plasma since S<sup>+</sup> is a minor product of dissociative ionization of SF<sub>6</sub> by electron impact.  $^{13}$  Molecular dissociation fractions in Ar/SF<sub>6</sub> ICPs generated in the same GEC cell were previously measured by Wang et al. 14 Although no data for pure SF<sub>6</sub> ICPs were reported, dissociation fractions in Ar/SF<sub>6</sub> ICPs exceeding 0.90 were reported for pressures ranging from 1.3 Pa (10 mTorr) to 6.7 Pa (50 mTorr)

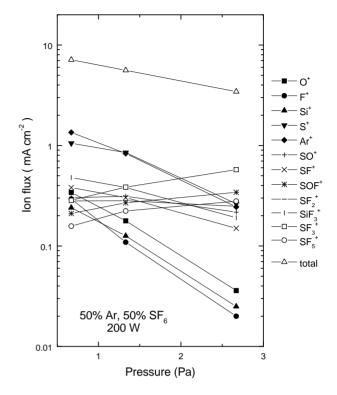


FIG. 2. Mass-resolved ion fluxes from 50% SF<sub>6</sub> / 50% Ar discharges at various pressures. All discharges were sustained at 200 W.

and for powers from 100 W to 300 W. It is likely that similarly large SF<sub>6</sub> dissociation fractions exist under our conditions as well.

The energy distributions of  $\mathrm{SF}_5^+$  and  $\mathrm{F}^+$  ions shown in Fig. 1(b) exhibit a distinctly bimodal structure indicative of rf modulation of the ions' energy as they traverse the plasma sheath, with the lightest ions experiencing the greatest modulation. <sup>15</sup> The center of the distribution, which corresponds to the average plasma potential, lies near 22 eV and is comparable to that observed for  $C_2F_6$  and c- $C_4F_8$ .

In order to extend the range of pressures and powers over which discharges could be operated, 50% Ar/50% SF<sub>6</sub> mixtures were used to investigate the trends in relative ion intensities with pressure and power. The results are shown in Figs. 2 and 3, respectively. The fluxes of Ar<sup>+</sup> and other atomic ions display the greatest sensitivity to changing pressure. In addition, the absolute and relative intensities of  $SF_3^+$ ,  $SF_5^+$  and  $SOF^+$  rise significantly with pressure. The dominant ion shifts from  $Ar^{+}$  at 0.67 Pa (5 mTorr) to  $SF_{3}^{+}$  at 2.67 Pa (20 mTorr). This trend may be attributable to relatively less dissoci-

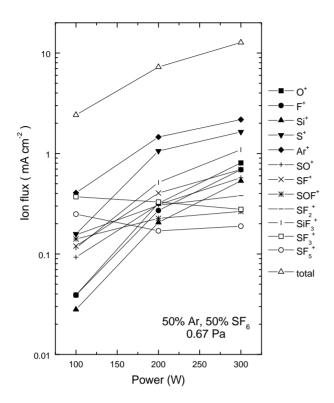


FIG. 3. Mass-resolved ion fluxes from 50% SF<sub>6</sub> / 50% Ar discharges at various powers. All discharges were sustained at 0.67 Pa (5 mTorr).

ation of the  ${\rm SF}_6$  feed gas with increasing pressure, and to a potentially increasing role of gas-phase ion-molecule reactions in the plasma. The significant fluxes of ions which contain either Si or O also illustrate the significance of plasma-surface and ion-molecule interactions to ion generation in these plasmas. Important ion-molecule processes which can significantly affect the contributions to the total ion flux of ions generated by plasma-surface and ion-molecule interactions, such as

$$Ar^{+} + SF_{6} \rightarrow SF_{5}^{+} + F + Ar, \tag{1}$$

and interactions with fragment ions, such as

$$SF_5^+ + SF_6 \to SF_3^+ + SF_6 + F_2,$$
 (2)

have appreciable rate constants. <sup>16,17</sup> In addition, ion conversion resulting from ion-molecule interactions and interactions with decomposition products are likely to be more significant at higher pressures.

Figure 3 shows the influence of discharge power on relative ion intensities in a 50% Ar/50% SF<sub>6</sub> mixture. The total ion flux increases a little more than a factor of five

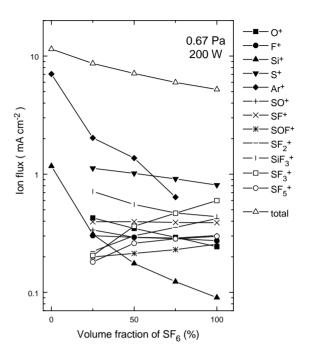
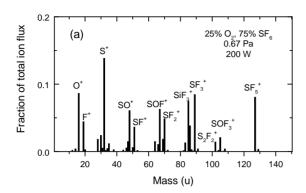


FIG. 4. Mass-analyzed ion fluxes in discharges containing  $SF_6$  for various mixtures with Ar. All discharges operated at 0.67 Pa (5 mTorr) and 200 W.

from 100 W to 300 W, with  $Ar^+$  consistently having the highest intensity. Nearly all the fluxes of significant ions increase monotonically with power. The intensities of  $SF_3^+$  and  $SF_5^+$ , however, decrease slightly in this range. A shift in the ion composition towards higher fluxes of lighter ions such as we observe could be explained by enhanced  $SF_6$  dissociation and decomposition at higher discharge powers.

The mass-resolved flux of positive ions extracted from discharges generated in different mixtures of  $SF_6$  and Ar at 0.67 Pa (5 mTorr) is shown in Fig. 4. As might be expected, the Ar<sup>+</sup> flux decreases as the  $SF_6$  concentration is raised, while the fluxes of heavier  $SF_x^+$  ions correspondingly increase.  $S^+$  remains the dominant sulfurcontaining ion in all mixtures which contain  $SF_6$ . In addition, the intensity of  $Si^+$  flux decreases substantially and that of  $SiF_3^+$  decreases to a lesser extent as a function of  $SF_6$  concentration. The relative fluxes of  $Si^+$  and  $SiF_3^+$  are small for the discharges investigated here as compared to that observed for discharges generated in fluorocarbons.<sup>7,9</sup>

Figure 5(a) shows the mass-resolved flux of positive



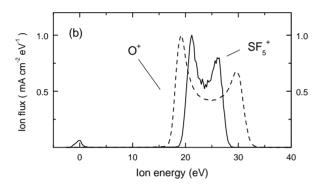


FIG. 5. (a) Mass spectrum of ions striking the grounded electrode in 75% SF $_6$  / 25% O $_2$  discharge sustained at 0.67 Pa (5 mTorr) and 200 W. (b) Normalized energy distributions of SF $_5^+$  (solid lines) and O $^+$  (dashed lines) ions under these conditions.

ions extracted from a discharge generated in a 75%  $SF_6/25\%$  O<sub>2</sub> discharge at 0.67 Pa (5 mTorr) and 200 W. Corresponding energy distributions of  $SF_5^+$  and of  $O^+$  for these operating conditions are shown in Fig. 5(b). Stable discharges could not be maintained with higher fractions of  $O_2$ . The ion spectrum and energy distributions shown in Fig. 5(b) closely resemble those observed in the pure SF<sub>6</sub> discharge operated under identical conditions shown in Fig. 1(a). Not surprisingly, the intensities of O<sup>+</sup> and sulfur oxyfluoride ions  $(SOF_x^+)$  are higher in the mixture than they are in pure SF<sub>6</sub>. The relative intensities of the lighter sulfur fluoride ions are diminished while that of SF<sup>+</sup><sub>5</sub> increases slightly, although S<sup>+</sup> remains the dominant ion. Similar analysis of the fluxes of 32 u and 34 u ions indicates roughly 20% of the flux of 32 u ions is due to  $O_2^+$ .

The pathways and rates of reaction between  $SF_6$  and oxygen cations and anions have been studied by Morris et  $al.^{18}$  Although  $O_2^+$  and  $O_2^-$  are unreactive with  $SF_6$ ,  $O_2^+$  and  $O_2^-$  undergo dissociative and non-dissociative charge

transfer, respectively, with  $SF_6$ . Dissociative charge transfer

$$O^+ + SF_6 \to SF_5^+ + FO \tag{3}$$

in particular may contribute to the observed relative increase of  $SF_5^+$  in  $O_2/SF_6$  discharges.

### IV. SUMMARY

Several ions of significant intensity have been observed from SF<sub>6</sub>, Ar/SF<sub>6</sub>, and O<sub>2</sub>/SF<sub>6</sub> ICPs. In addition to SF<sub>r</sub><sup>+</sup> ions, ions resulting from quartz etching and sulfur oxidation contribute moderately to the total ion flux. S<sup>+</sup> is the dominant sulfur-containing ion observed under most conditions, suggesting SF<sub>6</sub> dissociation and ion-molecule reactions play significant roles in determining the ion identities. In ICPs generated in 50% Ar/50% SF<sub>6</sub> mixtures, lighter atomic ions are the most sensitive to changes in either discharge pressure or power. This results in a shift of the ion composition from being comprised of mainly atomic ions at lower pressures to more massive molecular ions at higher pressures and to atomic ions contributing more heavily to the total ion flux at higher discharge powers. Ion conversion through ion-molecule reactions as well as from changes in the degree of SF<sub>6</sub> dissociation very likely contributes to these observed trends. The trends with SF<sub>6</sub> concentration are complex, although the intensities of nearly all  $SF_x^+$  ions rise with  $SF_6$  concentration. Addition of 25% O<sub>2</sub> to a 0.67 Pa (5mTorr), 200 W SF<sub>6</sub> discharge resulted in higher fluxes of O<sup>+</sup> and SF<sub>5</sub><sup>+</sup>, but produced little change in ion energies with respect to pure SF<sub>6</sub> discharges.

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